# NSN 5961-00-407-1950

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Inclosure Material:	Incl	osure	Mater	ial:
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Metal

**Overall Length:** 

0.260 inches

## Terminal Length:

1.500 inches

## **Overall Diameter:**

0.370 inches

#### Internal Configuration:

Junction contact

### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Terminal

#### Terminal Circle Diameter:

0.200 inches

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

175.0 breakdown voltage, collector-to-base, emitter open and 140.0 breakdown voltage, collector-to-base, emitter open and 8.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 500.00 milliamperes source cutoff current and 1.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

5.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### **Specification Data:**

80131-release5307 professional/industrial association specification

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

## Fiig:

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